

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

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Title of Invention

METHOD FOR CREATING A SELF-ALIGNED SOI DIODE BY
REMOVING A POLYSILICON GATE DURING PROCESSING

Application Number : 10/708912
Confirmation Number: 2911
First Named Applicant: Kiran Chatty
Attorney Docket Number: BUR920030180US1



Art Unit:

Examiner:

Search string: (5629544 or 5811857 or 6232163 or 6245600 or 6589823 or 6576958 or 6590264
or 20020119608 or 20030080386).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	5629544	1997-05-13	Voldman, et al			
	2	5811857	1998-09-22	Assaderaghi, et al			
	3	6232163	2001-05-15	Voldman, et al			
	4	6245600	2001-06-12	Geissler, et al			
	5	6589823	2003-07-08	Beebe, et al			
	6	6576958	2003-06-10	Ker, et al			
	7	6590264	2003-07-08	Ker, et al			

US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
	1	20020119608	2002-08-29	Ko, et al			
	2	20030080386	2003-05-01	Ker, et al			

Signature

Examiner Name	Date